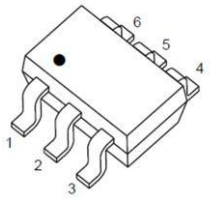
60VN-Channel MOSFET

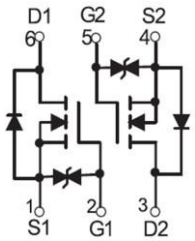
Product Summary

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
60V	3.5Ω@10V	340mA
	4Ω@4.5V	

SOT-363



Schematic diagram



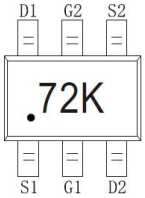
Feature

- High density cell design for Low $R_{DS(on)}$
- Voltage controlled small signal switch
- Rugged and reliable
- High saturation current capability
- ESD protected Gate HBM 2.5KV

Application

- Load Switch for Portable Devices
- DC/DC Converter

MARKING:



ABSOLUTE MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I_D	340	mA
Power Dissipation(1)	P_D	150	mW
Thermal Resistance from Junction to Ambient(1)	$R_{\theta JA}$	833	℃/W
Junction Temperature	T_J	150	℃
Storage Temperature	T_{STG}	-55~ +150	℃

MOSFET ELECTRICAL CHARACTERISTICS(T_a=25℃ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D =250μA	60			V
Zero gate voltage drain current	I_{DSS}	V_{DS} =48V,V_{GS} = 0V			1	μA
Gate-body leakage current	I_{GSS}	V_{GS} =±20V, V_{DS} = 0V			±10	μA
Gate threshold voltage*	$V_{GS(th)}$	V_{DS} =V_{GS}, I_D =250μA	1	1.4	2.5	V
Drain-source on-resistance*	$R_{DS(on)}$	V_{GS} =4.5V, I_D =200mA		1.4	4	Ω
		V_{GS} =10V, I_D =300mA		1.3	3.5	
Diode Forward Voltage	V_{SD}	V_{GS}=0V, I_S=300mA			1.5	V
Recovered charge	Q_r	V_{GS}=0V,I_S=300mA,V_R=25V, dI_s/dt=-100A/μs		30		nC
Dynamic characteristics**						
Input Capacitance	C_{iss}	V_{DS} =10V,V_{GS} =0V,f =1MHz			40	pF
Output Capacitance	C_{oss}				30	
Reverse Transfer Capacitance	C_{rss}				10	
Switching Characteristics**						
Turn-on delay time	$t_{d(on)}$	V_{GS}=10V,V_{DD}=50V,R_G=50Ω, R_{GS}=50Ω, R_L=250Ω			10	ns
Turn-off delay time	$t_{d(off)}$				15	
Reverse recovery Time	t_f	V_{GS}=0V,I_S=300mA,V_R=25V, dIs/dt=-100A/μs		30		
GATE-SOURCE ZENER DIODE						
Gate-Source Breakdown Voltage	BV_{GSO}	I_{gs}=±1mA (Open Drain)	±21.5		±30	V

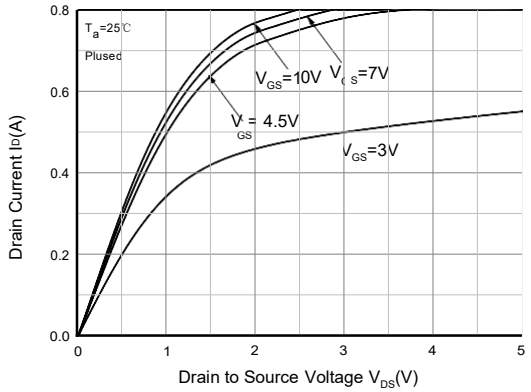
Notes:

*Pulse Test : Pulse Width ≤300μs, Duty Cycle ≤2%.

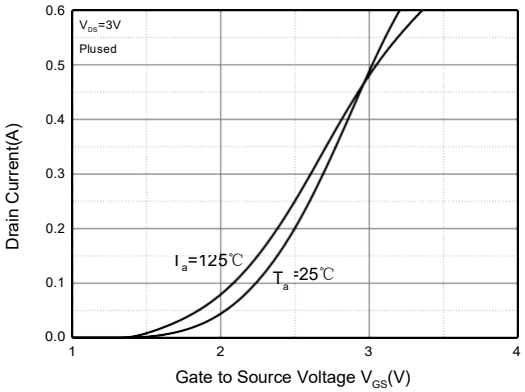
**These parameters have no way to verify.

Typical Electrical and Thermal Characteristic

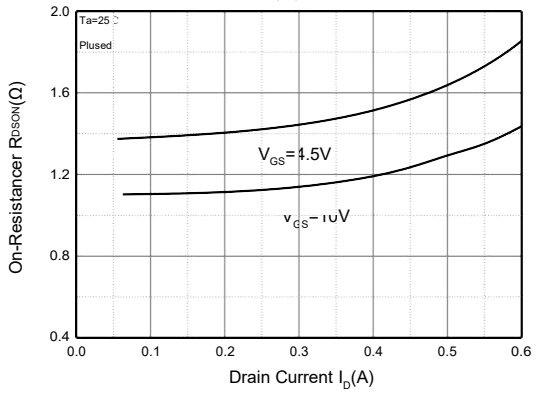
Output Characteristics



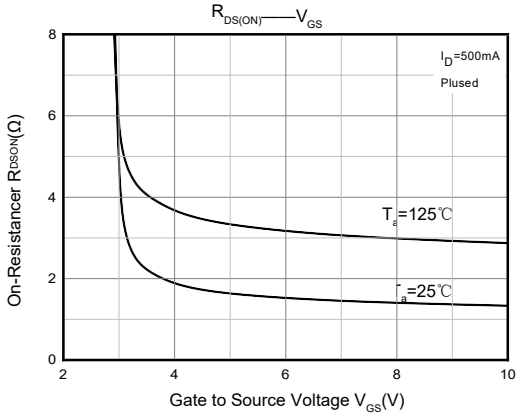
Transfer Characteristics



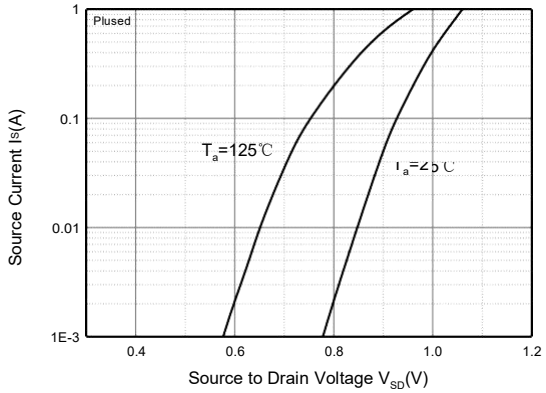
$R_{DS(ON)}$——I_D



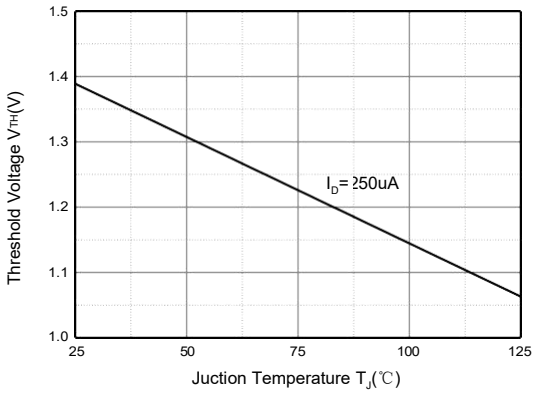
$R_{DS(ON)}$——V_{GS}



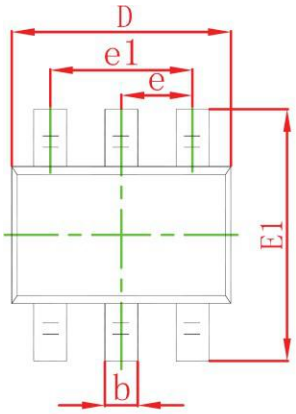
I_S——V_{SD}

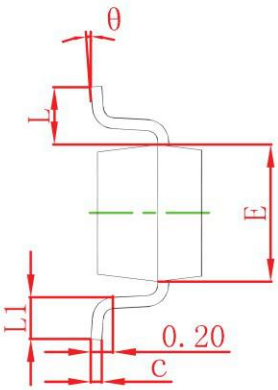


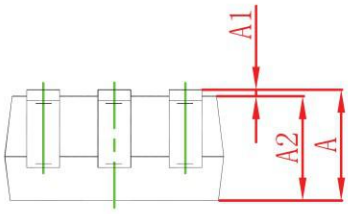
Threshold Voltage



SOT-363 Package Outline Dimensions



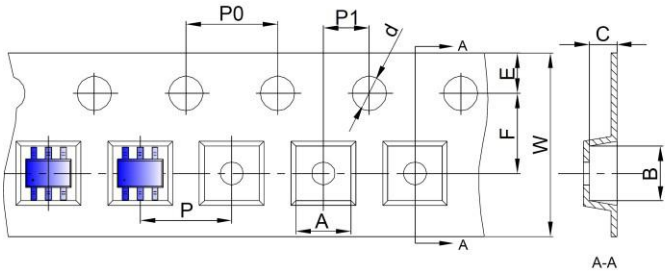




Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.100	0.150	0.004	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.400	0.085	0.094
e	0.650 TYP		0.026 TYP	
e1	1.200	1.400	0.047	0.055
L	0.525 REF		0.021 REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

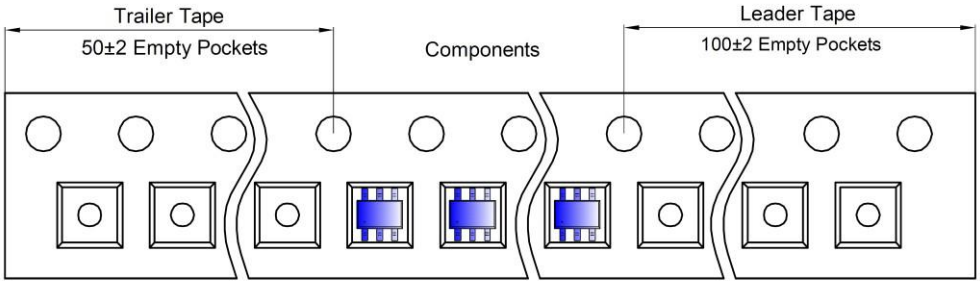
SOT-363 Tape and reel

SOT-363 Embossed Carrier Tape

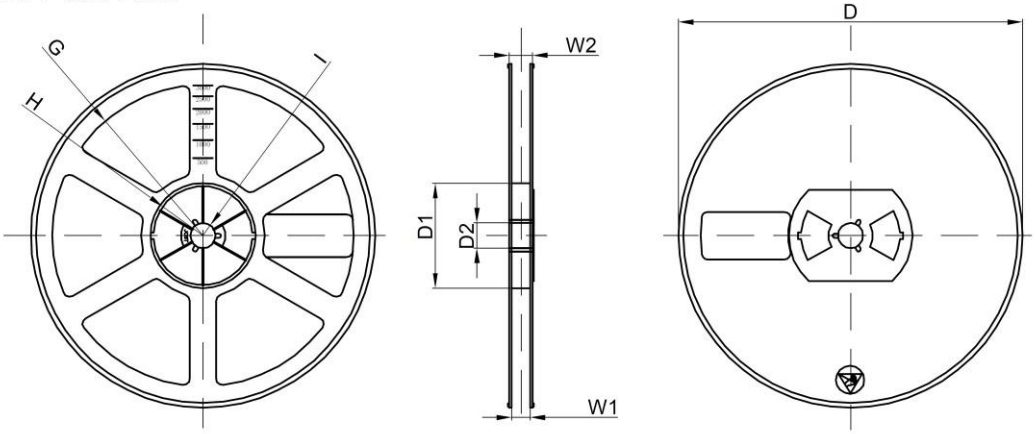


Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-363	2.25	2.55	1.20	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-363 Tape Leader and Trailer



SOT-363 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	